## 1 Introduction

jh3¿Junction design j/h3¿

The current NIST design (late 2012/early 2013) is the result of some trial and error over the past 6-7years. Unlike the initial work from Lafe Spietzs thesis at Yale, this design is intended to operate at frequencies up to 10 GHz. As such, we have implemented a very broadband launch/feed in a simple CPW-G conguration. In previous versions,we had some trouble with the excess attenuation in the line on chip which led to the junction so we have minimized the square count as well as buried the aluminum junction bilayer with 500nm of copper. The copper is not intended to drive the aluminum normal at low temperatures, but is mainly intended to minimize parasitic attenuation which fouls the noise temperature measurement. In addition, we have chosen a pretty transparent oxide so that we could use smaller junction overlaps. This is necessary to move the RC rolloff of the junction i, 10GHz, i.e. 2pF for a 50  $\Omega$  junction.

You can verify the rolloff yourself on a network analyzer and t it to get the capacitance. (You should check that the return loss is good at the frequency you will be measuring at anyway!) Since these are very transparent junctions, they can die pretty easily, so take the next section seriously.

jh3; Handling junctions; /h3;

Your SNTJ source probably arrived as a chip, bonded to a SMA launch sitting inside an overdesigned single-port sample box with a shorting cap on the SMA. The shorting cap is so that you don't blow up the junction. Usually this means, putting enough voltage across the junction (a couple of volts) such that you punch through the nice oxide that we, at NIST, worked hard at making just right. Basically, use conventional ESD precautions when you handle these devices. Since the junctions are bonded to the box ground (go ahead, look in side), its hard to blow them up by touching the SMA center pin by yourself since you are probably building an equipotential between your hands the moment you grab the box. However, this doesn't mean that whatever else you stick in that hole will be at the same potential. Its hard to go into a full on discussion of ESD handling precautions, but if you have blown up more than a couple of junctions, sit down and do some self-examination. You should make it a habit to ground whatever touches the SMA center pin and check that when you connect voltage/current biases that you know what potential that source is at prior to connecting. For this reason, it is often a GREAT idea to place enough dividers on a bias line such that its almost impossible to get the voltage too high. Resistive dividers also have the advantage in that they provide a path to ground for the junction

itself.

jh3; Chip design and bonding; /h3;

If you happen to blow up a junction, there are 5 others on the chip that you can use. The box and chip are designed such that you can slide the chip over and bond up another junction. First youll have to pull up the bonds on the chip that are already there. Youll have to do this under a microscope and have steady hands, but basically, you should be able to wiggle any bond wires that stuck to the chip with some tweezers, work hardening them until they break o. Then you can blow them away. After youve cleaned every thing up, you can slide the chip over to the next junction. Theyre currently stuck with Apiezon N-grease, so it should be pretty easy, but be gentle. I have been putting 4 bonds on either side of the signal line for the ground connections. This is pretty tight and probably overkill. It is important however to tack down the grounds near the unused SNTJs as well as a few bonds on the opposite side, bonding the chip ground to the box ground. It might not seem like its necessary, I know, but you can convince your self by measuring the return loss at room temperature on a network analyzer. The seemingly superuous bonds can make a dierence in eliminating spurious resonances up above 7 GHz. In any case, you should evaluate your bonding job on the network analyzer before placing in the fridge so that you don't have any surprises when youre cold. If you have done everything well, you should be near -20dB return loss up to 10 GHz. If you have resonances in S11 you will end up limiting the noise power that can leave the junction resulting in noise temperature that may look excessively high at those frequencies, since the shot noise measurement can only infer the system noise temperature reckoned for the entire chain between the junction and your noise measurement instrumentation.

;h3;.Box design ;/h3;.

The box design itself is certainly overkill and is the result of some OCD on my part. It is intended to hold the magnet (which really drives the aluminum normal) and also provide a light-tight seal at the top so that the device itself is really seeing cold metal and not anything else. It is made from OFHC. It used to be gold-plated to make people feel good, but I think this is largely unnecessary. However, you will probably need to hit it with ScotchBrite a little before you bolt it on to your cold plate. It is connectorized with a single Southwest Microwave eld-replaceable male SMA anged connector(P/N213-500SF) with a 12 mil pin + teon sleeve to feed through the 0.125 box wall. You can use any other anged connector you like as long as it takes the 12 mil pin standard. The solid model and drawings are available to anybody that wants them. Note: we have started putting male connectors on these

boxes so you can mount them directly on the RF+DC end of an Anritsu K250 bias tee without an adapter (we also have heard anecdotally that the Anritsu K251 (the one with the gold-colored body) breaks when cold!).

;h3;Embedded magnet;/h3;

The box is as big as it is so that it can accommodate a beefy cylindrical rare earth magnet (0.3750.2). Depending on what we had available this will either be one magnet or two thinner magnets stacked. As delivered, this magnet will have a little bit of Apiezon N grease gobbed into the well which will, presumably, keep it from rattling around when mounted on your fridge. If you are skeeved out by having giant magnets near your sample (are your isolators and circulators actually well-shielded, too?) then you can take out the magnet. When youre cold youll have to bias well above the gap to get the noise temperature and gain and you will give up the possibility of extracting temperature. Also note that the Southwest SMA connector that weve mounted is slightly magnetic itself, so if your worried about stuff like that then youll have to replace it with a nonmagnetic version (like the ones from EZ-Form). If you are really paranoid you can replace the 0-80 screws holding the board down, too, but in many of the boxes these are now titanium so theyre already ok. NOTE: If you decide to not use the magnet and have to bias well above the gap, keep in mind that the resulting noise output can be enough to drive some ampliers into bad nonlinear regimes. Specifically, Josephson parametric ampliers with critical currents of less than 20 A are known to saturate just above the point that the shot noise overtakes the quantum noise on the curve. If none of this makes sense, but you think you might have a related problem, send me(jose.aumentado@nist.gov)a note!

jh3; Noise power formula; /h3;

The formula for the noise power emitted by the shot noise tunnel junction (SNTJ) in the quantum regime (kBT; hf) is:

$$N = Gk_BBT_N + \left(\frac{eV + hf}{2k_BT}\right) \coth\left(\frac{eV + hf}{2k_BT}\right) + \left(\frac{eV - hf}{2k_BT}\right) \coth\left(\frac{eV - hf}{2k_BT}\right)$$

G is the power gain of the entire system, kB is the Boltzmann constant, B is the bandwidth, TN is the noise temperature, V is the junction voltage, h is Plancks constant and f is the frequency at which the noise is measured. This is the full double-coth functi on which yields the quantum noise at-bottom feature. Although the double-coth is overkill for higher temperatures, you can still use whatever t routine you cookedup for the double-coth t, it just might take a little longer. In the end,however, if you are just concerned with noise temperature, then the quantum noise stuff and even the temperature

dont matter. You can x the temperature to something close and just do linear ts on the asymptotes to extract the gain and the noise temperature. ;h3;.Operation;/h3;.

Determine the junction resistance/Voltage bias ratio I nd that the resistance of the junctions can increase a few s over their room temperature values when cooled to dilution temperatures. As such, if youre really gungho about having a 50 junction, youll do best to start with something like 48 or 49. Since the goal for these devices is an accurate assessment of the noise temperature, getting closeto 50 is important, but how close is close? If your source impedance (junction impedance) is 41, then the fraction of noise power that can propagate out is

$$\eta = 1|\Gamma|^2 = 0.99$$

so youll only end up with a 1

This is the number that youll use for your t. Its important to get this right since the noise temperatures that you will infer will scale with your measurement of the junction voltage through  $k_B$ . Figure 0.1: Bias resistor conguration for determining the ratio between the applied bias VB and the junction bias VJ. If you use a current source in place of VB you can determine the resistance and convince yourself that your reection loss will probably be good enough.

;h3; How do you set the bias resistance values? ;/h3;

If youre after noise temperature and your SNTJ is cold enough to be well into the quantum regime, then youll be happy if you have something like 10hf/e, that is, something that well exceeds the corners on the quantum noise at bottom. If youre at 6GHz, then this turns out to be something like 25V. Since I like to have my bias sources scaled so that they swing about 1V for the range of interest, this means a divider ratio of something like 1:40,000. If you dont use any room temperature dividers, you can use a single bias resistor value of 2 M. I usually end up using a divider at room temperature and using something like 100k so that I can measure temperature at higher temperatures as a sanity check.

## 2 Measure the noise

Although you can, in principle, demodulate the output of your amp chain using a diode rectifier, youll have to play games setting the ltering of the room temperature mixer output and youll have to think about one more thing. I think that its far easier to demodulate the output of the SNTJ at a

given frequency by using a standard spectrum analyzer in a triggered, zero span acquisition at the frequency that you care to measure. I use the Agilent E4407B for this purpose. Make sure to set it to sample each bin and not pull the max/min at each point. The E4407B also lets you set the display to linear Watts. Open up the resolution bandwidth as wide as you need to, usually less than 10 MHz on a typical instrument. This will yield the noise curve integrated over this bandwidth, so if your interested in getting the noise over a narrower bandwidth then you can crank it down, but be prepared to wait longer. Anyhow, with the trace averaging in the instrument you can accumulate averaged shot noise mustache traces quickly and easily by syncing a triangle sweep on the bias. Output the data however you like and perform your t using the scaling ratio VJ/VB that you found with your 3 probe measurement above. Since these automated spectrum analyzers do a lot under the hood, you have to make sure that however it congures its own internal attenuators to level its incoming signals, that its noise oor is dominated by your amplification chain. Set up your bias sweep so that you can see a good noise mustache, sweeping out something like  $10 k_B T$  and setting the power scale on your analyzer so that the max noise fills out the y-scale. If you shut off your cryogenic HEMT, then the noise power shown on the analyzer should be very close to zero. This is an indication that the cryogenic HEMT is dominating your system noise. If it doesn't reach zero, then you have other stuff later in the chain that is contributing significant noise and you have some troubleshooting to do.

## 3 HEY! My system noise looks higher than the spec sheet!

Your rst inclination might be to think that somehow the SNTJ is giving you a wrong answer, probably because the noise looks high and you really want to go out and say that you have quantum-limited added noise. Before you come to this conclusion, you have to remember what the SNTJ gives youit can only yield the total system noise between the junction and the spectrum analyzer. This includes loss contributions inside the SNTJ box between the junction and the SMA, all of the rections at every connection, the loss in every circulator, bias tee, and normal metal cable as well as the temperature of those cables. If you are unsure about what these pieces add, or skeptical that they should add so much, then sit down and calculate and then show someone else as a check. We are happy to help you gure out whats going on. As a point of reference, though, be aware that many of the

system noise numbers that many groups have stated in their papers are just plain wrong. It is typical for instance, for CalTech HEMT amplier to have 5K noise temperature, but after all of the loss between a DUT at the mixing chamber and the input of the HEMT at 4 K, we nd it typical to see between 10-15 K total system noise.

jh3¿Attribution;/h3¿

Some groups have asked how to attribute credit to us (co-authorship, acknowledgement, or nothing at all?). It really depends on what piece the SNTJ plays in your experiment, but in the end we should just have a conversation to make sure were all on the same page.

jh3¿More stuff?j/h3¿

These are just random notes o the top of my head. If you have other tips and suggestions that you think should be included, then feel free to write something up and send it to me at jose.aumentado@boulder.nist.gov and Ill work on including it. Also,if you would like example Matlab code+data,just send us a note.